

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET

2SK3748— High-Voltage, High-Speed Switching Applications

Features

- · Low ON-resistance, low input capacitance, ultrahigh-speed switching
- High reliability (Adoption of HVP process)
- · Attachment workability is good by Mica-less package
- · Avalanche resistance guarantee

Specifications

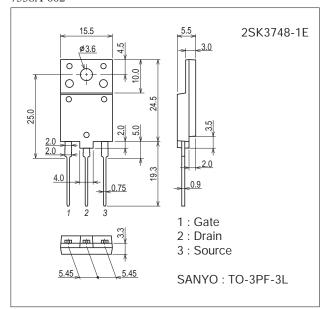
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		1500	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID*		4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	8	Α
Allowable Dower Dissinction	D-		3.0	W
Allowable Power Dissipation	PD	Tc=25°C	65	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		165	mJ
Avalanche Current *2	IAV		4	Α

^{*}Shows chip capability

Package Dimensions

unit : mm (typ) 7538A-002



Product & Package Information

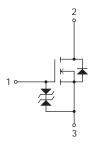
Package : TO-3PF-3LJEITA, JEDEC : SC-94

• Minimum Packing Quantity: 30 pcs./magazine

Marking

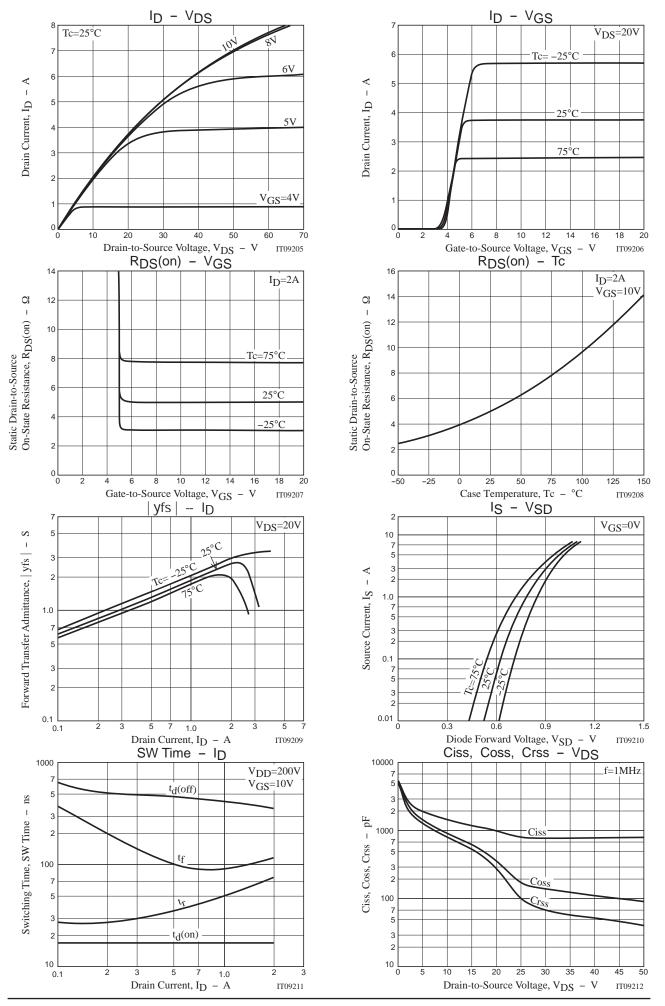
Electrical Connection

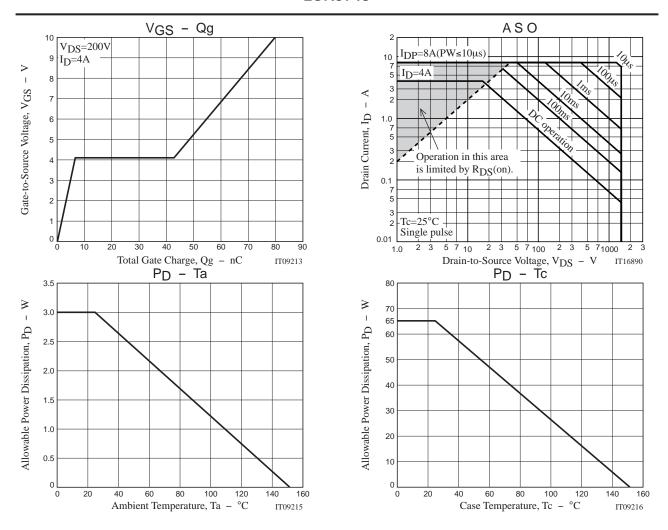




^{*1} V_{DD}=50V, L=20mH, I_{AV}=4A (Fig.1)

^{*2} L≤20mH, single pulse



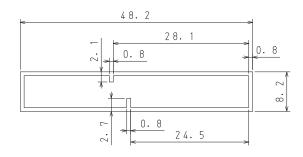


Magazine Specification

2SK3748-1E

1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			Packing format		
I dona 80 Mamo	Magazine	Inner box	Outer box	Inner BOX	Outer BOX	
TO-3PF-3L	30	360	1440	12 magazines contained	SPD-LV0010 4 inner boxes contained Dimensions:mm (external) 590x225x178	



Tolerance=±0.2mm
Thickness=0.8±0.2mm
Length =508.0±1mm
Material =PVC or PET
(Antistatic treatment)

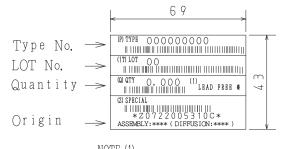
3. Storage method to magazine

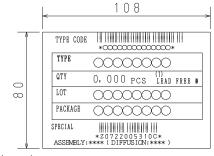


4. Inner box label (unit:mm)



It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



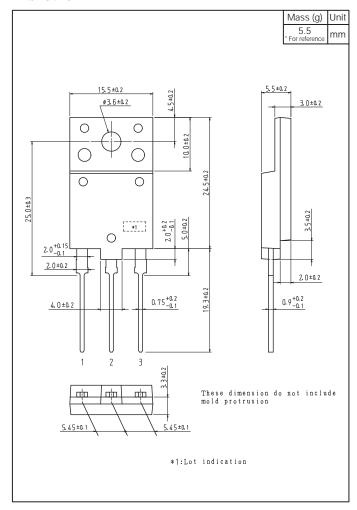


The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label		JEITA Phase
LEAD FRE	E 3	JEITA Phase 3A

Outline Drawing

2SK3748-1E



Note on usage: Since the 2SK3748 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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